

**TRIACS**

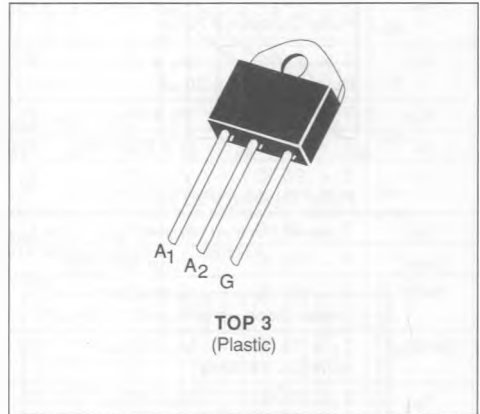
- GLASS PASSIVATED CHIP
- $I_{GT}$  SPECIFIED IN FOUR QUADRANTS
- INSULATING VOLTAGE 2500  $V_{RMS}$
- UL RECOGNIZED (E81734)

**DESCRIPTION**

This new design of plastic insulated power triacs offers maximum efficiency with maximum ease of mounting.

**ADVANTAGES**

- NO TAPPING REQUIRED FOR FIXING
- EXCELLENT THERMAL IMPEDANCE AND HIGH RELIABILITY CONSTRUCTION


**ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter		Value	Unit
$I_{T(RMS)}$	RMS on-state Current (360° conduction angle)	$T_C = 75\text{ °C}$	40	A
$I_{TSM}$	Non Repetitive Surge Peak on-state Current ( $T_j$ initial = 25 °C - Half sine wave)	$t = 8.3\text{ ms}$	315	A
		$t = 10\text{ ms}$	300	
$I^2t$	$I^2t$ Value for Fusing	$t = 10\text{ ms}$	450	$A^2s$
$di/dt$	Critical Rate of Rise of on-state Current (1)	Repetitive $F = 50\text{ Hz}$	10	$A/\mu s$
		Non Repetitive	50	
$T_{S19}$ $T_j$	Storage and Operating Junction Temperature Range		- 40 to 125 - 40 to 125	$^{\circ}C$ $^{\circ}C$

Symbol	Parameter	BTA 41-					Unit
		200B	400B	600B	700B	800B	
$V_{DRM}$	Repetitive Peak off-state Voltage (2)	200	400	600	700	800	V

(1)  $I_G = 1\text{ A}$   $di/dt = 1\text{ A}/\mu s$

(2)  $T_j = 125\text{ °C}$ .

**THERMAL RESISTANCES**

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction to Ambient	50	$^{\circ}C/W$
$R_{th(c-h)}$	Contact (case-heatsink) with Grease	0.2	$^{\circ}C/W$
$R_{th(j-c)}\text{ DC}$	Junction to Case for DC	1.2	$^{\circ}C/W$
$R_{th(j-c)}\text{ AC}$	Junction to Case for 360 ° Conduction Angle ( $F = 50\text{ Hz}$ )	0.9	$^{\circ}C/W$

**GATE CHARACTERISTICS** (maximum values)

$P_{GM} = 40 \text{ W}$  ( $t_p = 10 \mu\text{s}$ )       $I_{GM} = 10 \text{ A}$  ( $t_p = 10 \mu\text{s}$ )  
 $P_{G(AV)} = 1 \text{ W}$        $V_{GM} = 16 \text{ V}$  ( $t_p = 10 \mu\text{s}$ )

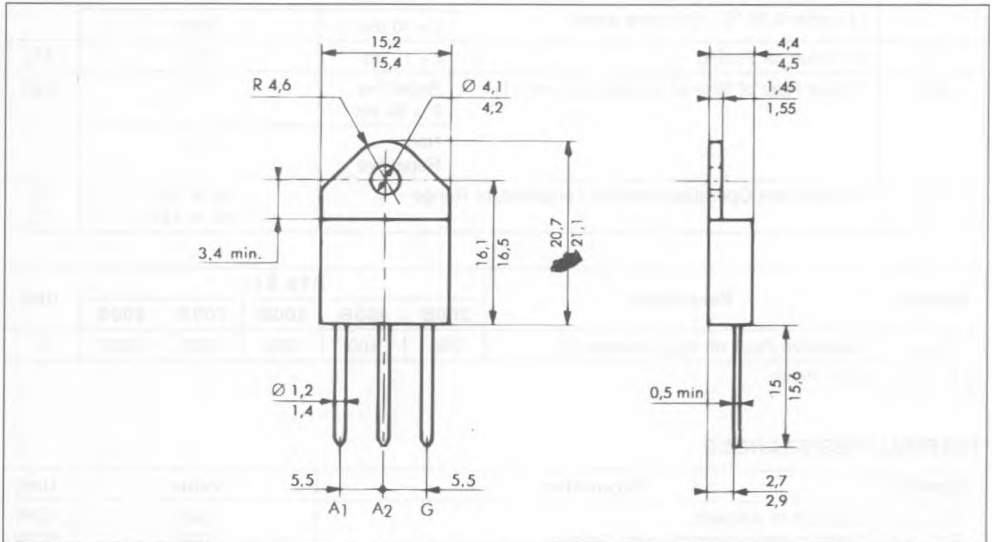
**ELECTRICAL CHARACTERISTICS**

Symbol	Test Conditions	Quadrants	Min.	Typ.	Max.	Unit
$I_{GT}$	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $R_L = 33 \text{ } \Omega$ Pulse Duration > 20 $\mu\text{s}$	I-II-III	1		50	mA
		IV	1		100	
$V_{GT}$	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $R_L = 33 \text{ } \Omega$ Pulse Duration > 20 $\mu\text{s}$	I-II-III-IV			1.5	V
$V_{GD}$	$T_j = 125 \text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$	I-II-III-IV	0.2			V
$I_H^*$	$T_j = 25 \text{ }^\circ\text{C}$ $I_T = 500 \text{ mA}$ Gate Open			30	80	mA
$I_L$	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = 12 \text{ V}$ $I_G = 200 \text{ mA}$ Pulse Duration > 20 $\mu\text{s}$	I-II-III-IV			100	mA
$V_{TM}^*$	$T_j = 25 \text{ }^\circ\text{C}$ $I_{TM} = 60 \text{ A}$ $t_p = 10 \text{ ms}$				1.8	V
$I_{DRM}^*$	$T_j = 125 \text{ }^\circ\text{C}$ $V_{DRM}$ Specified			1.5	6	mA
$dv/dt^*$	$T_j = 125 \text{ }^\circ\text{C}$ Gate Open Linear Slope up to $V_D = 67 \% V_{DRM}$		250			V/ $\mu\text{s}$
$(dv/dt)_c^*$	$T_C = 75 \text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 60 \text{ A}$ $(di/dt)_c = 18 \text{ A/ms}$		5			V/ $\mu\text{s}$
$t_{GT}$	$T_j = 25 \text{ }^\circ\text{C}$ $V_D = V_{DRM}$ $I_T = 60 \text{ A}$ $I_G = 1 \text{ A}$ $di_G/dt = 10 \text{ A}/\mu\text{s}$	I-II-III-IV		2.5		$\mu\text{s}$

\* For either polarity of electrode A<sub>2</sub> voltage with reference to electrode A<sub>1</sub>.

**PACKAGE MECHANICAL DATA**

TOP 3 Plastic



Cooling method : by conduction (method C)  
 Marking : type number  
 Weight : 5 g

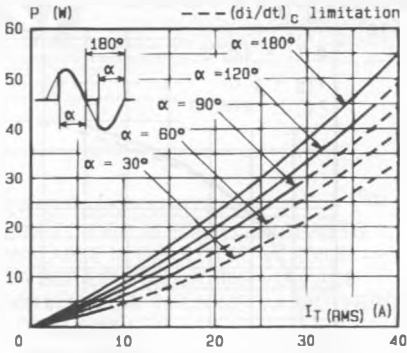


Fig.1 - Maximum mean power dissipation versus RMS on-state current ( $F = 60 \text{ Hz}$ ).

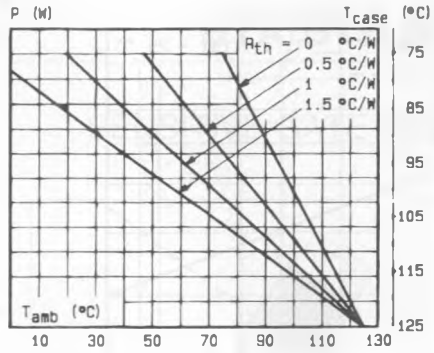


Fig.2 - Correlation between maximum mean power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for different thermal resistances heatsink + contact.

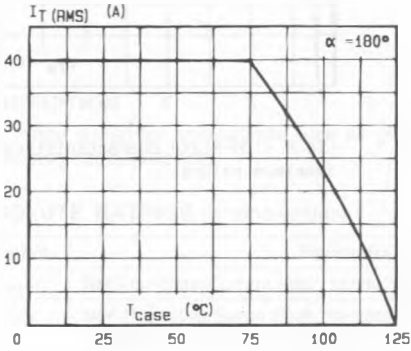


Fig.3 - RMS on-state current versus case temperature.

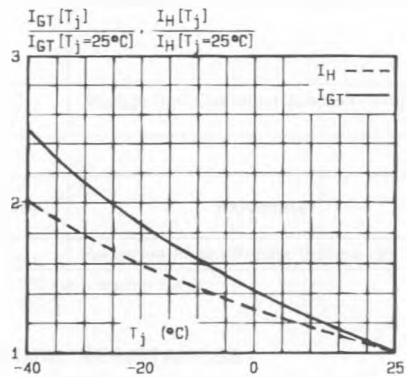


Fig.5 - Relative variation of gate trigger current and holding current versus junction temperature.

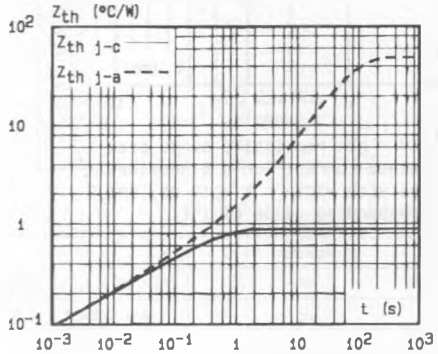


Fig.4 - Thermal transient impedance junction to case and junction to ambient versus pulse duration.

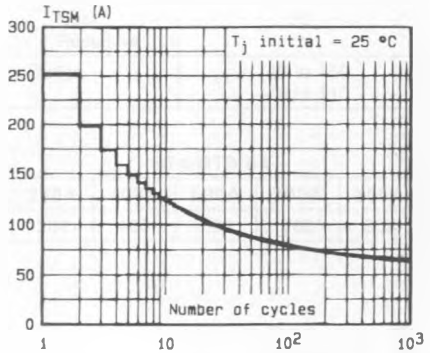


Fig.6 - Non repetitive surge peak on-state current versus number of cycles.

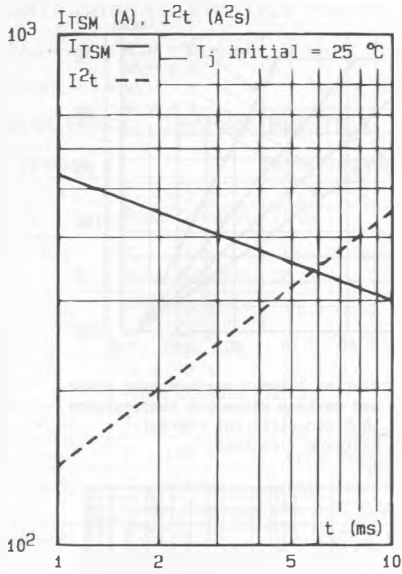


Fig.7 - Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $t \leq 10$  ms, and corresponding value of  $I^2t$ .

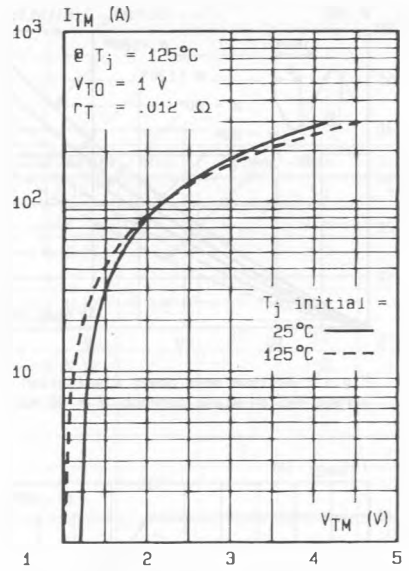


Fig.8 - On-state characteristics (maximum values).